



#### **Product data sheet**

#### **1. General description**

Standard reverse recovery power diode in a 2-lead TO220 package.



#### 2. Features and benefits

- Low forward voltage drop
- Low leakage current
- High voltage capability
- High inrush current capability

#### 3. Applications

- Oring diode
- Bypass diode
- Input rectifier for bridge configurations

### 4. Quick reference data

able 1. Q	uick reference data						
Symbol	Parameter	Conditions	Notes	Values			Unit
Absolute	maximum rating						
$V_{\text{RRM}}$	repetitive peak reverse voltage				1600		V
$\mathbf{I}_{\mathrm{F(AV)}}$	average forward current	δ = 0.5 ; square-wave pulse; T <sub>mb</sub> ≤ 97 °C; Fig. 1; Fig. 2; Fig. 3			35		A
I <sub>FSM</sub>	non-repetitive peak forward current	t <sub>p</sub> = 10 ms; T <sub>j(init)</sub> = 25 °C; sine-wave pulse; <u>Fig. 4</u>		400			A
		$t_{\rm p}$ = 8.3 ms; $T_{j(\text{init})}$ = 25 °C; sine-wave pulse			435		А
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static ch	aracteristics						
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 35 A; T <sub>j</sub> = 25 °C; <u>Fig. 6</u>		-	1.18	1.40	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 1600 V; T <sub>j</sub> = 25 °C		-	-	50	μA

# 5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		
2	А	anode	ן ך <b>ר</b> ו	K <u>– K</u> – A 001aaa020
mb	mb	mounting base; connected to cathode		

# 6. Ordering information

Table 3. Ordering information								
Type number	Package	Orderable part number	Packing	Small packing	Package	Package		
	name		method	quantity	version	issue date		
WND35P16	TO220-2L	WND35P16Q	Tube	50	TO220d-2L	13-Oct-2022		

## 7. Marking

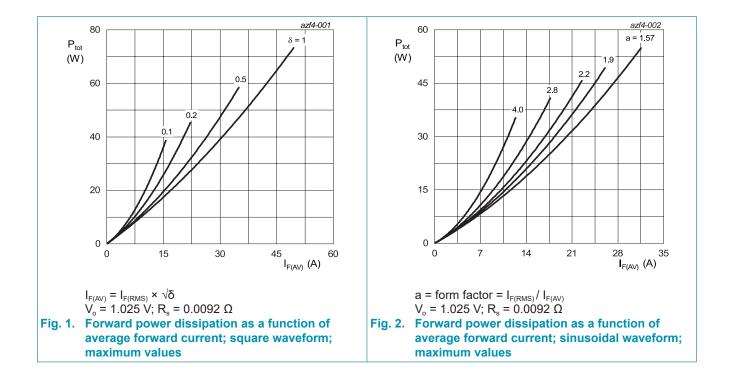
Table 4. Marking codes					
Type number	Marking codes				
WND35P16	WND35P16				

## 8. Limiting values

#### Table 5. Limiting values

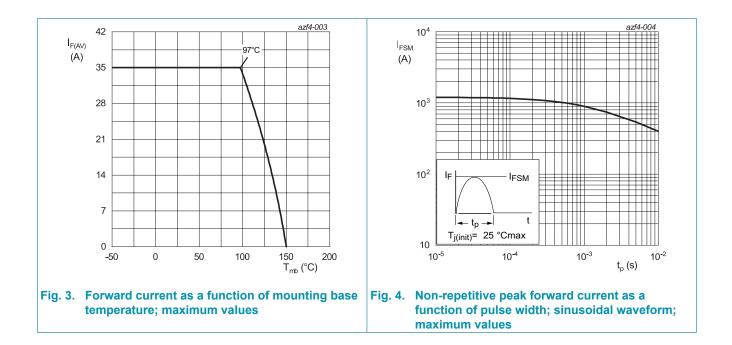
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
$V_{\text{RRM}}$	repetitive peak reverse voltage			1600	V
$V_{\text{RWM}}$	crest working reverse voltage			1600	V
V <sub>R</sub>	reverse voltage	DC		1600	V
$I_{F(AV)}$	average forward current	δ = 0.5 ; square-wave pulse; T <sub>mb</sub> ≤ 97 °C; Fig. 1; Fig. 2; Fig. 3		35	A
I <sub>FSM</sub>	non-repetitive peak forward current	$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4		400	A
		$t_p$ = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse		435	А
l <sup>2</sup> t	I <sup>2</sup> t for fusing	$t_p = 10 \text{ ms}; T_{j(init)} = 25 \text{ °C}; \text{ sine-wave pulse};$		800	A <sup>2</sup> s
T <sub>stg</sub>	storage temperature			-40 to 150	°C
Tj	junction temperature			-40 to 150	°C



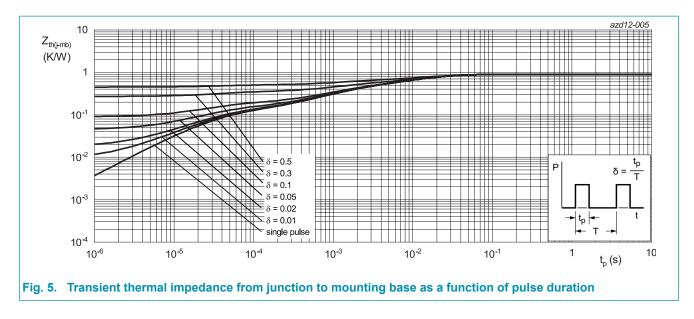
Standard power diode

WND35P16



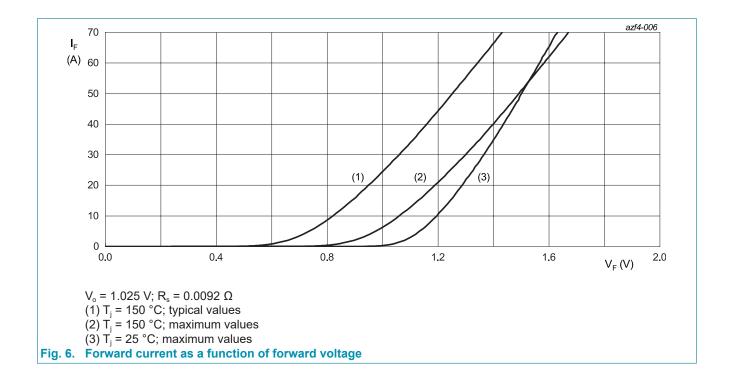
## 9. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	<u>Fig. 5</u>	-	-	0.9	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air	-	60	-	K/W

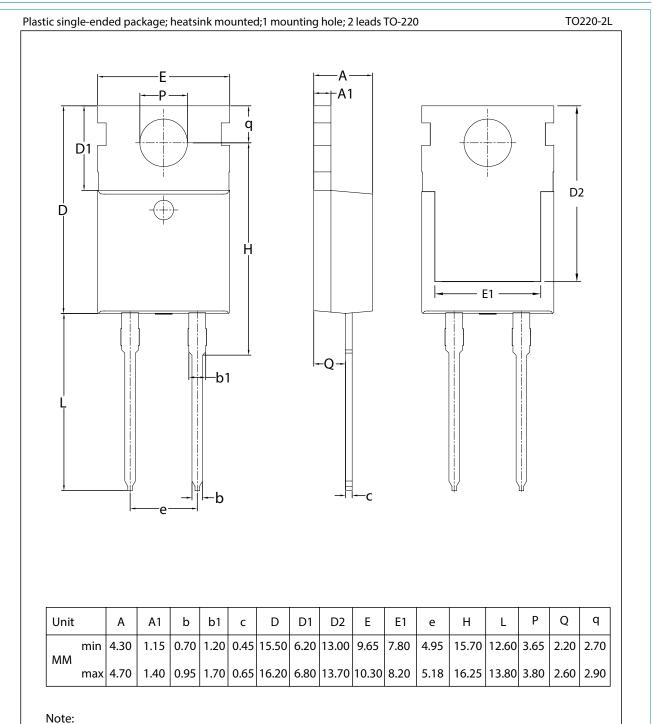


## **10. Characteristics**

Table 7. Cl	naracteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static cha	racteristics						
$V_{\rm F}$	forward current	I <sub>F</sub> = 35 A; T <sub>j</sub> = 25 °C; <u>Fig. 6</u>		-	1.18	1.40	V
		I <sub>F</sub> = 35 A; T <sub>j</sub> = 150 °C; <u>Fig. 6</u>		-	1.15	1.35	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 1600 V; T <sub>j</sub> = 25 °C		-	-	50	μA
		V <sub>R</sub> = 1600 V; T <sub>j</sub> = 150 °C		-	-	1	mA



### **11. Package outline**



1. All dimensions don't include mold flash and metal protrusion.

# WND35P16

#### Standard power diode

## 12. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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